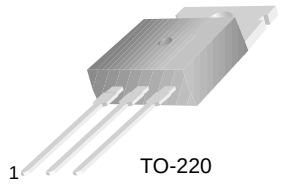
FAIRCHILD SEMICONDUCTOR™

KSC2518

High Speed, High Voltage Switching

- Low Collector Saturation Voltage
- Specified of Reverse Biased SOA With Inductive Load



TO-220

1.Base 2.Collector 3.Emitter

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	500	V
V_{CEO}	Collector-Emitter Voltage	400	V
V_{EBO}	Emitter-Base Voltage	7	V
I_C	Collector Current (DC)	4	A
I_{CP}	*Collector Current (Pulse)	8	A
I_B	Base Current (DC)	1	A
P_C	Collector Dissipation (T_C=25°C)	40	W
T_J	Junction Temperature	150	°C
T_{STG}	Storage Temperature	- 55 ~ 150	°C

* PW≤350μs, Duty Cycle≤10%

Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
V_{CEO}(sus)	Collector-Emitter Sustaining Voltage	I_C = 2A, I_{B1} = 0.4A, L = 1mH	400		V
V_{CEX}(sus)1	Collector-Emitter Sustaining Voltage	I_C = 2A, I_{B1} = -I_{B2} = 0.4A T_a = 125°C, L = 180μH, Clamped	450		V
V_{CEX}(sus)2	Collector-Emitter Sustaining Voltage	I_C = 4A, I_{B1} = 0.8A, -I_{B2} = 0.4A T_a= 125°C, L = 180μH, Clamped	400		V
I_{CBO}	Collector Cut-off Current	V_{CB} = 400V, I_E = 0		10	μA
I_{CER}	Collector Cut-off Current	V_{CE} = 400V, R_{BE} = 51Ω @ T_C= 125°C		1	mA
I_{CEX1} I_{CEX2}	Collector Cut-off Current	V_{CE} = 400V, V_{BE}(off) = -1.5V V_{CE} = 400V, V_{BE}(off) = -1.5V @ T_C= 125°C		10 1	μA mA
I_{EBO}	Emitter Cut-off Current	V_{EB} = 5V, I_C = 0		10	μA
h_{FE1} h_{FE2}	* DC Current Gain	V_{CE} = 5V, I_C = 0.3A V_{CE} = 5V, I_C = 1.5A	20 10	80	
V_{CE}(sat)	* Collector-Emitter Saturation Voltage	I_C = 1.5A, I_B = 0.3A		1	V
V_{BE}(sat)	* Base-Emitter Saturation Voltage	I_C = 1.5A, I_B = 0.3A		1.5	V
t_{ON}	Turn ON Time	V_{CC} = 150V, I_C = 2A I_{B1} = - I_{B2} = 0.4A R_L = 75Ω		1	μs
t_{STG}	Storage Time			2.5	μs
t_F	Fall Time			0.7	μs

* Pulse Test: PW≤350μs, Duty Cycle≤2% Pulsed

h_{FE} Classification

Classification	R	O	Y
h_{FE1}	20 ~ 40	30 ~ 60	40 ~ 80

Typical Characteristics

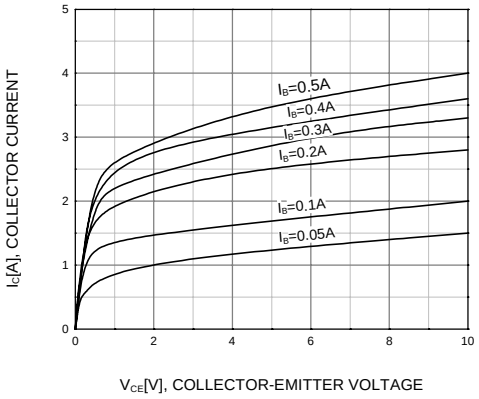


Figure 1. Static Characteristic

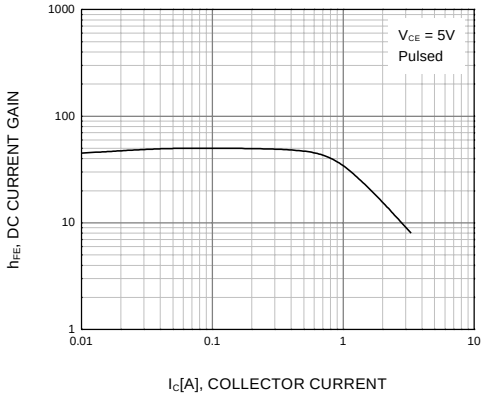


Figure 2. DC current Gain

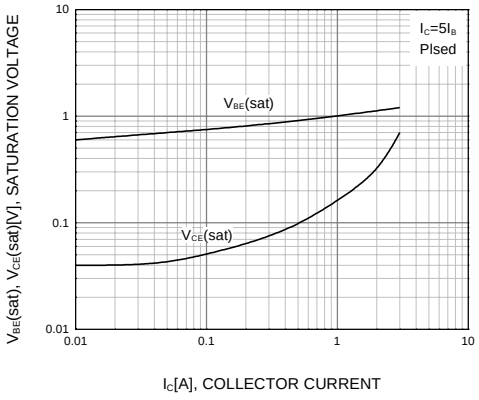


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

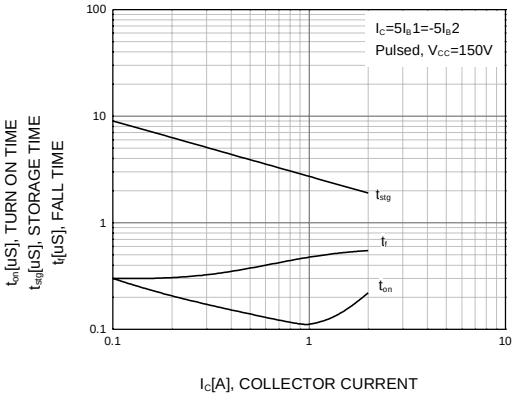


Figure 4. Turn On, Storage and Fall Time vs Collector Current

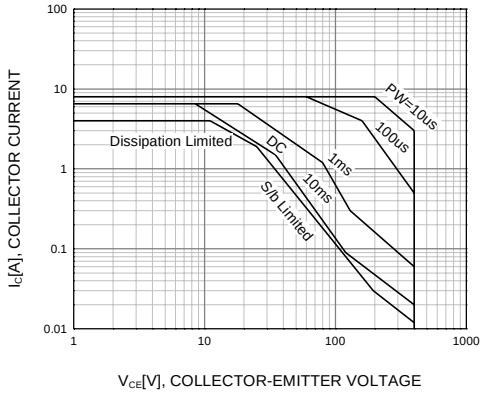


Figure 5. Forward Bias Safe Operating Area

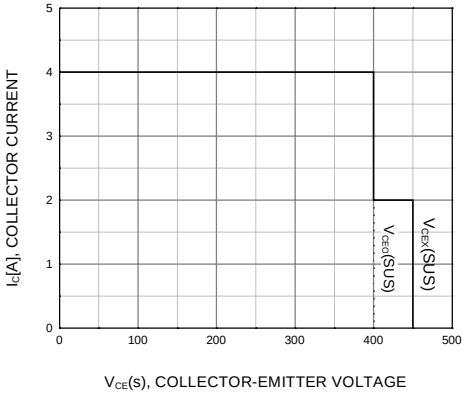


Figure 6. Reverse Bias Safe Operating Area

Typical Characteristics (Continued)

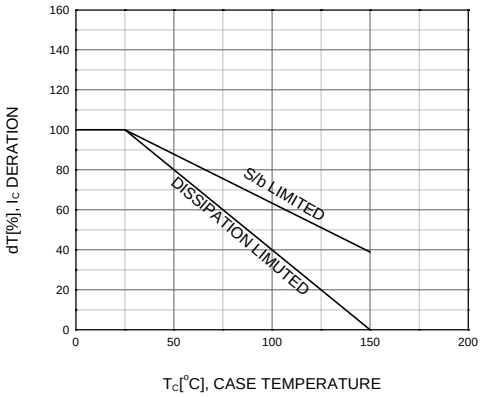


Figure 7. Derating Curve of Safe Operating Areas

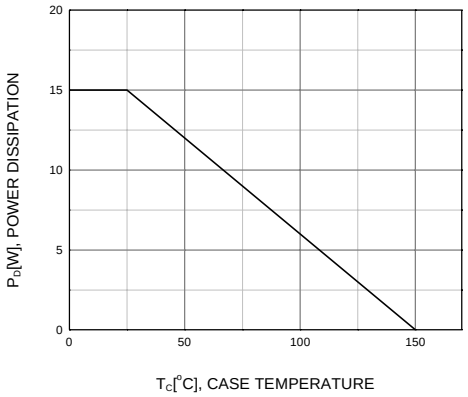
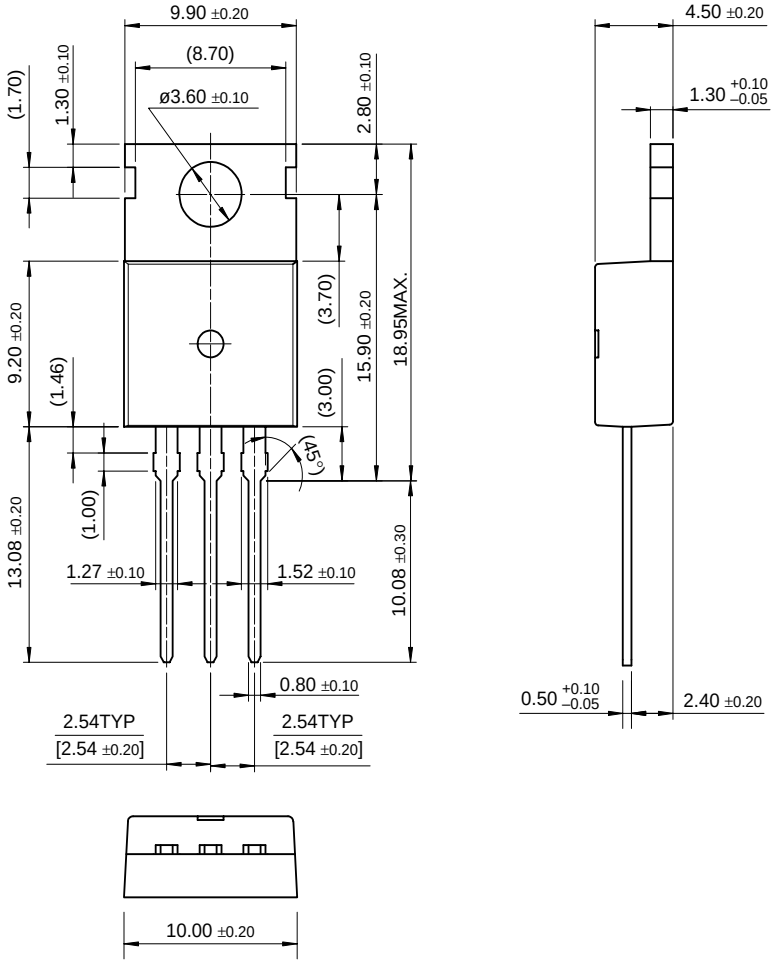


Figure 8. Power Derating

Package Demensions

TO-220



Dimensions in Millimeters

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